Ramgarhia Polytechnic College, Phagwara



Electrical Engineering Department

Head of Department:	S. Jasvir Singh
Name of the Faculty:	Er. Rahul Bahl
Discipline:	Electrical Engineering Department
Semester:	3 rd
Subject:	Analog Electronics
Lesson Plan Duration:	16 Weeks

RATIONALE

At present, electronics gadgets are being extensively used in various manufacturing processes in industries, power system operations, communication systems, computers etc. Even for an electrical diploma holder, it is absolutely necessary to have a basic understanding of electronic components, their function and applications. This understanding should facilitate in operation and maintenance equipment, which are electronically controlled. In this course, topics like semi-conductor Diodes, Bipolar transistors, rectifiers, single stage and multistage amplifiers and field effect transistors have been included.

Learning Outcomes

After undergoing this course, the students will be able to:

- CO1. Use P.N. junction as rectifier.
- CO2. Use Zener diode as voltage stabilizer Use various batteries and their care
- CO3. Use bi-polar transistors and its application as an amplifier and as a switch.
- CO4. Analyse amplifier and enhance the gain of amplifier
- CO5. Use unipolar transistors as amplifier
- CO6. Identify and testing of various active and passive components such as resistor, inductor, capacitor, diode and transistor

PO ⇒	PO1	PO2	PO3	PO4	PO5	PO6	PO7
00 J							
CO1							
CO2							
CO3							
CO4							
CO5							
CO6							
CO7							
CO8							
CO9							

Syllabus

Units	Details	Hours
1.	Semiconductor Diodes. 1.1 PN Junction, mechanism of current flow in PN junction, drift and diffusion currents, depletion layer, potential barrier, effect of forward and reverse biasing in a PN junction. Concept of junction capacitance in forward and reverse biased conditions. Breakdown mechanism 1.2 Ideal diode, Semiconductor diode characteristics, static and dynamic resistance 1.3 Use of diode as half wave and full wave rectifiers (centre tapped and bridge type), relation between DC output and AC input voltage, rectifier efficiency 1.4 Concept of ripples, filter circuits – shunt capacitor, series inductor, and pie (π) filters and their applications 1.5 Diode ratings/specifications 1.6 Various types of diodes such as zener diode, varactor diode, schottky diode, light emitting diode, tunnel diode, photo diode; their working characteristics and applications 1.7 Zener diode and its characteristics	(12 hrs)
2.	 1.8 Use of zener diode for voltage stabilization 2.1 Concept of junction transistor, PNP and NPN transistors, their symbols and mechanism of current flow 2.2 Transistor configurations: common base (CB), common emitter (CE) and common collector (CC), current relation and their input/output characteristics: comparison of the three configurations 	(08 hrs)
3.	 Transistor Biasing and Stabilization 3.1 Transistor biasing, its need, operating point, effect of temperature on the operating point of a transistor and need of stabilization of operating point. 3.2 Different biasing circuits, limitations, simple problems to calculate operating point in different biasing circuits. Use of Thevenin's theorem to determine operating point 3.3 Concept of h-parameters of a transistor 3.4 Use of data book to know the parameters of a given transistor). 	(12 hrs)
4.	Single-Stage Transistor Amplifiers 4.1 Single stage transistor amplifier circuit in CE configuration, function of each component 4.2 Working of single stage transistor amplifier, physical and graphical explanation, phase reversal 4.3 Concept of DC and AC load line 4.4 Voltage gain of single stage transistor amplifier using characteristics of the device 4.5 Concept of input and output impedance	(12 hrs)

	4.6 AC equivalent circuit of single stage transistor amplifiers						
	4.7 Calculation of voltage gain using AC equivalent circuit						
	4.8 Frequency response of a single stage transistor amplifier						
5.	Multi-Stage Transistor Amplifiers	(10 hrs)					
	5.1 Need of multi-stage transistor amplifiers – different types of						
	couplings, their purpose and applications.						
	5.2 Knowledge of various terms such as voltage gain, current gain,						
	power gain, frequency response, decibel gain and band width						
	5.3 RC coupled two-stage amplifiers, circuit details, working, frequency						
	response, applications 89						
	5.4 Loading effect in multistage amplifiers						
	5.5 Elementary idea about direct coupled amplifier, its limitations and						
	applications						
	5.6 Transformer coupled amplifiers, its frequency response. Effect of						
	coefficient of coupling on frequency response. Applications of						
	transformer						
6.	Field Effect Transistor (FET)	(08 hrs)					
	6.1 Construction, operation, characteristics and applications of a N channel JFET	()					
	and P channel JFET						
	6.2 JFET as an amplifier						
	6.3 Types, construction, operation, characteristics and applications of a MOSFET						
	6.4 Comparison between BJT, JFET and MOSFET						

Reference Books:

1. Basic Electronics and Linear Circuit by NN Bhargava, Kulshreshta and SC Gupta, Tata McGraw Hill Education Pvt Ltd, New Delhi.

2. Electronic Principles by SK Sahdev, Dhanpat Rai & Co., New Delhi

3. Principles of Electrical and Electronics Engineering by VK Mehta; S Chand and Co., New Delhi

4. Electronic Components and Materials by SM Dhir, Tata McGraw Hill Publishing Company Pvt Ltd, New Delhi.

5. Principles of Electronics by SK Bhattacharya and Renu Vig, SK Kataria and Sons, Delhi

6. Electronics Devices and Circuits by Millman and Halkias; McGraw Hill.

7. Principles of Electronics by Albert Paul Malvino; Tata McGraw Hill Education Pvt Ltd, New Delhi.

8. Basic Electronics – Problems and Solutions by Albert Malvino and David J. Bates; Tata McGraw Hill Education Pvt Ltd, New Delhi.

- 9. Basic Electronics by J.S. Katre, Sandeep Bajaj, Tech. Max. Publications, Pune.
- 10. Analog Electronics by DR Arora, Ishan Publications, Ambala City.

Delivery/Instructional

Methodologies

Sr.No.	Description
1.	Chalk and Talk
2.	PowerPoint Presentation

Assessment Methodologies

Sr. No.	Description	Туре
1.	Student Assignment	Direct
2.	Test	Direct
3.	Board Examination	Direct
4.	Student Feedback	Direct

Gaps in the syllabus - to meet industry/profession requirements

S.NO.	DESCRIPTION	PROPOSED ACTIONS	PO MAPPING
	N/A	N/A	N/A

Topics beyond syllabus/advanced topics

Units	Details	Hours
N/A	N/A	N/A

Web Source References

Sr. No.	URL
1.	https://nptel.ac.in/

Lesson Plan

Week	Theory		Practical	
	Lecture		Practical	
	Day		Day	
	1 st	PN Junction, mechanism of		1(a)Identification and
		current flow in PN junction,		testing of electronic
		drift and diffusion currents,		components such as
1 st		depletion layer, potential	1	resistor, inductor,
		barrier	1.	capacitor, diode,
	2 nd	effect of forward and		transistor and different
		reverse biasing in a PN		types of switches used in
		junction. Concept of		Electronic circuits
		junction capacitance in		b) Measurement of
		forward and reverse biased		resistances using
		conditions. Breakdown		multimeter and their
		mechanism		comparison with colour
	3 rd	Ideal diode, Semiconductor		code values
		diode characteristics, static		Group I
		and dynamic resistance		

	4 th	Use of diode as half wave and full wave rectifiers (centre tapped and bridge type)		
2 nd	5 th 6 th	relation between DC output and AC input voltage, rectifier efficiency	2.	1(a)Identification and testing of electronic components such as resistor, inductor, canacitor, diode
	7 th	Concept of ripples, filter circuits – shunt capacitor,		transistor and different types of switches used in
	8 th	series inductor, and pie (π) filters and their applications		Electronic circuits b) Measurement of resistances using multimeter and their comparison with colour code values Group II
	9 th	Diode ratings/specifications		To plot V-I characteristics of a Semiconductor diode and to calculate its
3 rd	11 th	Zener diode and its characteristics	3.	static and dynamic resistance Group I
	12 th	Use of zener diode for voltage stabilization		
	13 th	Bi-polar Transistors		To plot V-I characteristics of a Semiconductor
4 th	14 th	Concept of junction		diode and to calculate its static and dynamic
	15 th	transistor, PNP and NPN transistors	4.	Group II
	16 th	Transisitor symbols and mechanism of current flow		
	17 th	Transistor configurations		a) To plot V-I characteristics of a zenor
5 th	18 th	common base (CB), common emitter (CE)		diode and finding its reverse breakdown
	19 th		5.	

	20 th	common collector (CC), current relation and their input/output characteristics; comparison of the three configurations		a zenor diode voltage stabilizer circuit using PCB Group I
6 th	21st 22 nd	Transistor Biasing and Stabilization Transistor biasing, its need	6.	a) To plot V-I characteristics of a zenor diode and finding its reverse breakdown voltage b) Fabrication of a zenor diode voltage stabilizer circuit using PCB Group II
	23 rd	REVISION		
	24 th	1 st Sessional Test (Tentative)		
7 th	25 th	Operating point, effect of temperature on the operating point of a transistor and need of stabilization of operating point	7.	4. Observation of input and output wave shapes of a half-wave rectifier and verification of relationship between dc output and ac input
	26 th	Different biasing circuits,		voltage Group I
	27 th	 limitations, simple problems to calculate operating point in different biasing circuits 		
	28 th	Use of Thevenin's theorem to determine operating point		
8 th	29 th	Concept of h-parameters of		4. Observation of input and output wave shapes
	30 th	a transistor	8.	of a half-wave rectifier and verification of relationship between dc output and ac input voltage Group II
	31 st	Use of data book to know		
	32 nd	the parameters of a given transistor		
	33 rd	Single stage transistor		5. Observation of input and output wave shapes
	34 th	amplifier circuit in CE		of a full wave rectifier

- + h		configuration, function of	_	and verification of
9 th	ərth		9.	and ac input voltage
	35	Working of single stage		Group I
	a cth	transistor amplifier,		
	36"	physical and graphical		
		explanation, phase reversal		
	37 th	Concept of DC and AC load	10.	5. Observation of input and output wave shapes of a full wave rectifier and verification of
		line		
	38 th 39 th	Voltage gain of single stage		
		transistor amplifier using		
10 th		characteristics of the device		relationship between dc
		Concept of input and		Group II
	40th	_ output impedance.		
	40	AC equivalent circuit of		
	a a st	single stage transistor		C Observation of input
	4130	ampimers		b. Observation of input
				of a full wave rectifier
	42 nd			with (i) shunt capacitor)
11 th		Calculation of voltage gain		(ii) series inductor (iii)
			11.	filter circuits
	43 rd			Group I
	44 th	REVISION		
12 th	45 th	РТМ		6. Observation of input
	_			and output wave shapes
	46 th	2 nd Sessional Test		of a full wave rectifier
		(Tentative)		with (i) shunt capacitor)
	⊿ 7th	Erequency response of a	12.	(ii) series inductor (iii)
	47**	single stage transistor		filter circuits
	4 O th	amplifier		Group II
	48"			
13 th	49 th	Nood of multi stage		7. Plotting input and
	50 th	Need of multi-stage transistor amplifiers – different types of couplings.		output characteristics of
				a transistor ill CB
		their purpose and	13.	Group I
		applications.		oub .

	52 nd	Knowledge of various terms such as voltage gain, current gain, power gain, frequency response, decibel		
		gain and band width		
	53 rd	RC coupled two-stage		7. Plotting input and output characteristics of
14 th	54 th	amplifiers, circuit details, working, frequency response, applications	14	a transistor in CB configuration Group II
	55 th	Loading effect in multistage amplifiers)		
	56 th			
	57 th	Liementary idea about direct coupled amplifier, its limitations and applications		8.Plotting input and output characteristics of
15 th	58 th	Transformer coupled amplifiers, its frequency response. Effect of coefficient of coupling on frequency response. Applications of transformer coupled amplifiers	15.	Group I
	59 th			
	60 th	Construction, operation, characteristics and		
16 th	61 st	applications of a N channel JFET and P channel JFET JFET as an amplifier PTM	16.	8.Plotting input and output characteristics of a transistor in CE configuration Group II
	62 nd			
	63 rd	Types, construction, operation, characteristics and applications of a MOSFET Comparison between BJT, JFET and MOSFET		
	64 th	3 ^{ra} Sessional Test (Tentative)		

NBA has defined the following seven POs for an Engineering diploma graduate:

i) **Basic and Discipline specific knowledge**: Apply knowledge of basic mathematics, science and engineering fundamentals and engineering specialization to solve the engineering problems.

ii) **Problem analysis:** Identify and analyze well-defined engineering problems using codified standard methods.

iii) **Design/ development of solutions**: Design solutions for well-defined technical problems and assist with the design of systems components or processes to meet specified needs.

iv) **Engineering Tools, Experimentation and Testing**: Apply modern engineering tools and appropriate technique to conduct standard tests and measurements.

v) **Engineering practices for society, sustainability and environment**: Apply appropriate technology in context of society, sustainability, environment and ethical practices.

vi) **Project Management**: Use engineering management principles individually, as a team member or a leader to manage projects and effectively communicate about well-defined engineering activities.

vii) **Life-long learning**: Ability to analyze individual needs and engage in updating in the context of technological changes.

Program Specific Outcomes (PSOs)

PSOs are a statement that describes what students are expected to know and be able to do in a specialized area of discipline upon graduation from a program. Program may specify 2-4 program specific outcomes, if required.

These are the statements, which are specific to the particular 11 program. They are beyond POs. Program Curriculum and other activities during the program must help in the achievement of PSOs along with POs.